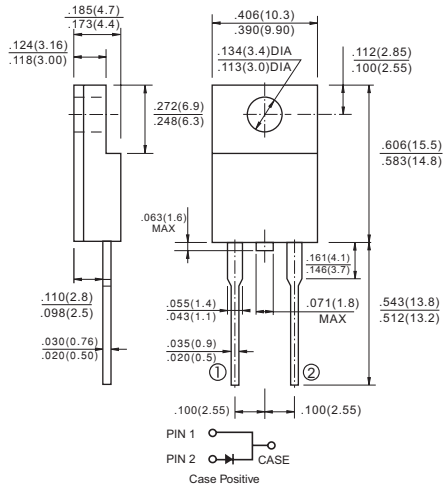


MBRF735 - MBRF7150

Isolated 7.5 AMPS. Schottky Barrier Rectifiers
ITO-220AC



Features

- ✧ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✧ Metal silicon rectifier, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guarding for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

- ✧ Cases: ITO-220AC molded plastic body
- ✧ Terminals: Pure tin plated, lead free. solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs. max
- ✧ Weight: 0.08 ounce, 2.24 grams

Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	MBRF	Units
		735	745	750	760	790	7100	7150	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	105	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	V
Maximum Average Forward Rectified Current See Fig. 1	$I_{(AV)}$	7.5							A
Peak Repetitive Forward Current (Square Wave, 20KHz) at $T_c=105^\circ\text{C}$	I_{FRM}	15.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150							A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0			0.5				A
Maximum Instantaneous Forward Voltage at (Note 2) $I_F=7.5\text{A}, T_c=25^\circ\text{C}$ $I_F=7.5\text{A}, T_c=125^\circ\text{C}$ $I_F=15\text{A}, T_c=25^\circ\text{C}$ $I_F=15\text{A}, T_c=125^\circ\text{C}$	V_F	-	-	0.75	-	0.92	-	1.02	V
Maximum Instantaneous Reverse Current @ $T_c=25^\circ\text{C}$ at Rated DC Blocking Voltage (Note 1) @ $T_c=125^\circ\text{C}$	I_R	0.1	-	0.1	-	0.1	-	5.0	mA mA
Voltage Rate of Change (Rated V_R)	dV/dt	10,000							V/ μS
Typical Junction Capacitance	C_j	350			280		200		pF
Maximum Thermal Resistance, (Note 3)	$R_{\theta JC}$	7.0							$^\circ\text{C}/\text{W}$
Operating Junction Temperature Range	T_J	-65 to +150							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +175							$^\circ\text{C}$

- Notes:
1. 2.0us Pulse Width, $f=1.0\text{ KHz}$
 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
 3. Mounted on Heatsink Size of 2 in x 3 in x 0.25in Al-plate.

RATINGS AND CHARACTERISTIC CURVES (MBRF735 THRU MBRF7150)

FIG.1- FORWARD CURRENT DERATING CURVE

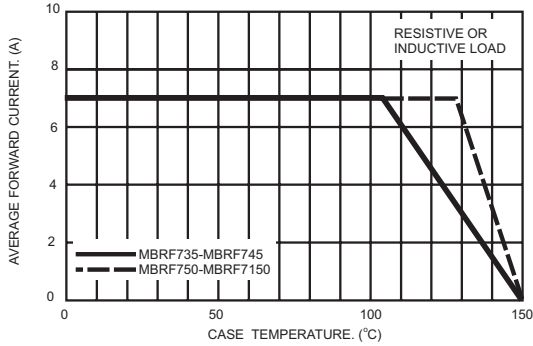


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

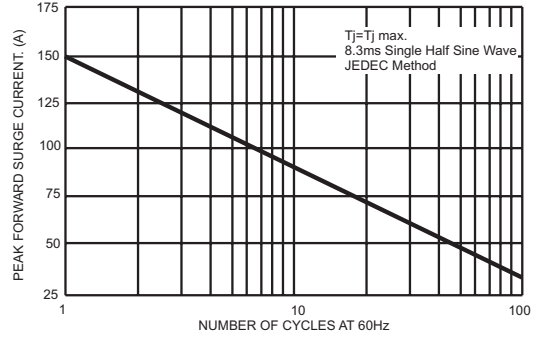


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

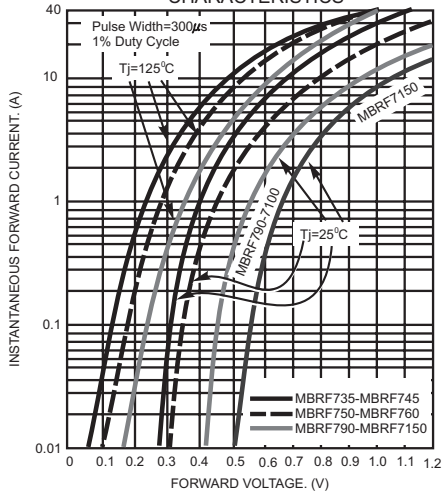


FIG.4- TYPICAL REVERSE CHARACTERISTICS

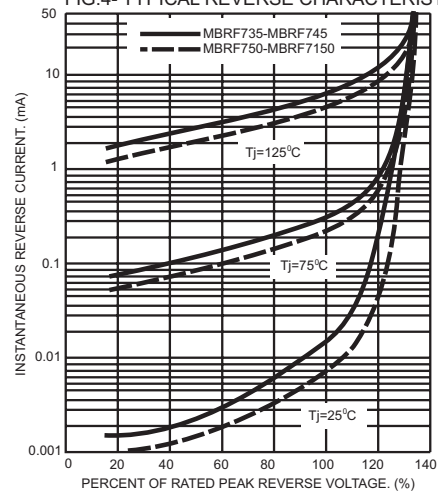


FIG.5- TYPICAL JUNCTION CAPACITANCE

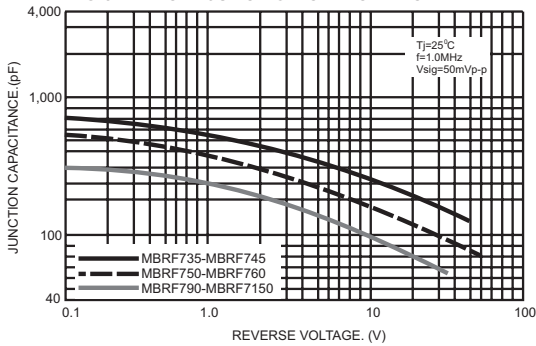


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS

